

# 2SC5852

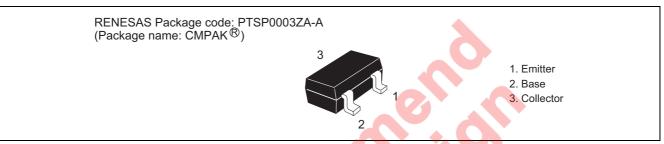
# Silicon NPN Epitaxial Planar

REJ03G0762-0100 (Previous ADE-208-1481) Rev.1.00 Aug.10.2005

#### **Features**

VHF amplifier, local oscillator

### **Outline**



\*CMPAK is a trademark of Renesas Technology Corp.

# **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Collector to base voltage	V <sub>CBO</sub>	30	V
Collector to emitter voltage	V <sub>CEO</sub>	20	V
Emitter to base voltage	V <sub>EBO</sub>	4	V
Collector current	Ic	20	mA
Collector power dissipation	P <sub>C</sub> *	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

<sup>\*</sup>Value on the glass epoxy board (10 mm x 10 mm x 0.7 mm)

### **Electrical Characteristics**

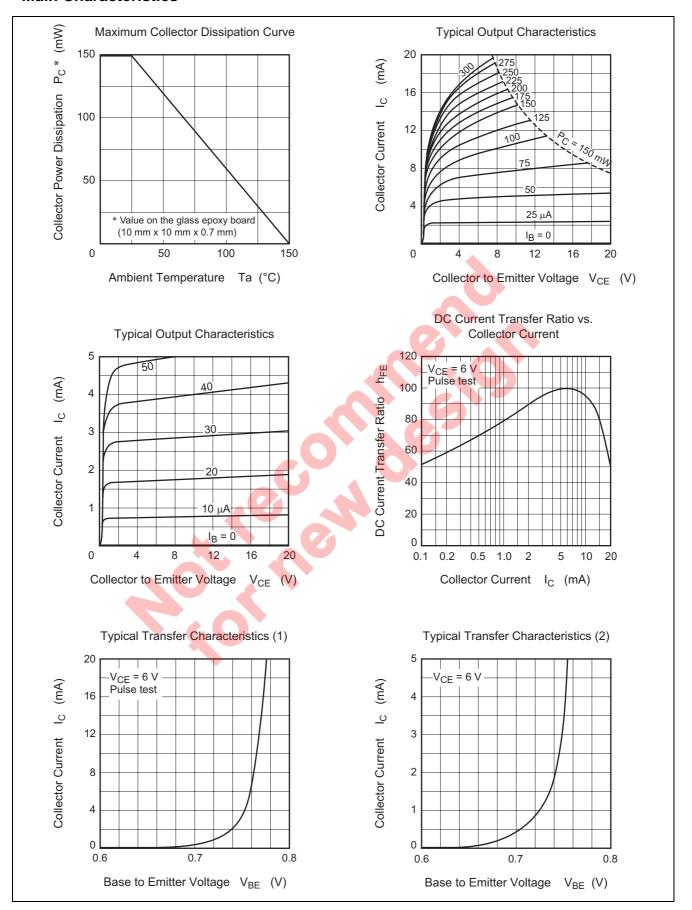
 $(Ta = 25^{\circ}C)$ 

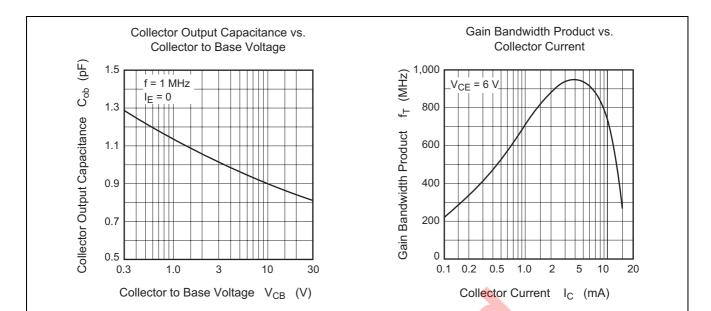
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	30	_	_	V	$I_C = 10 \mu A, I_E = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	20	_	_	V	$I_C = 1 \text{ mA}, R_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	4	_	_	V	$I_E = 10 \mu A, I_C = 0$
Collector cutoff current	I <sub>CEO</sub>	_	_	0.5	μΑ	V <sub>CE</sub> = 10 V, R <sub>BE</sub> = ∞
Emitter cutoff current	I <sub>EBO</sub>	_	_	0.5	μΑ	$V_{EB} = 2 \text{ V}, I_{C} = 0$
DC current transfer ratio	h <sub>FE</sub> *1	60	_	200		$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	$V_{CE(sat)}$	_	0.17	_	V	$I_C = 20 \text{ mA}, I_B = 4 \text{ mA}$
Base to emitter voltage	$V_{BE}$	_	0.72	_	V	$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA}$
Gain bandwidth product	f⊤	_	940	_	MHz	$V_{CE} = 6V$ , $I_C = 5$ mA
Collector output capacitance	$C_{ob}$	_	0.9	_	pF	$V_{CB} = 10 \text{ V}, I_E = 0, f = 1 \text{ MHz}$

Notes: 1. The 2SC5852 is grouped by  $h_{\text{FE}}$  as follows.

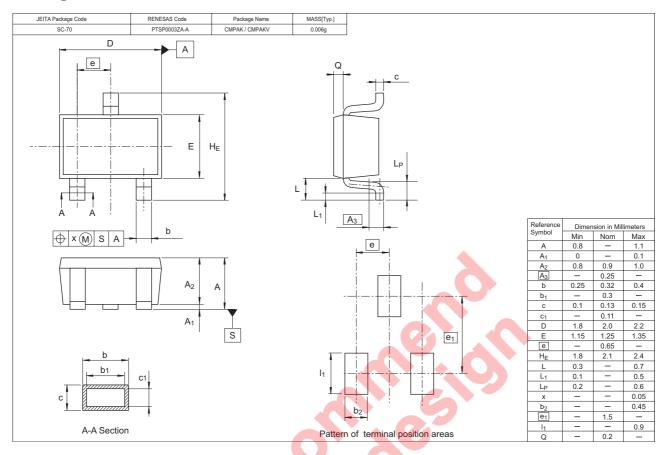
Grade B C
Mark QB QC
h <sub>FE</sub> 60 to 120 100 to 200
h <sub>FE</sub>   60 to 120   100 to 200

### **Main Characteristics**





## **Package Dimensions**



## **Ordering Information**

Part Name	Quantity		Shipping Container
2SC5852QBTL-E	3000	φ 1	78 mm Reel, 8 mm Emboss Taping
2SC5852QCTL-E			

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.

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